





MBR130HW SURFACE MOUNT SCHOTTKY BARRIER DIODE



Features

- Low Turn-on Voltage
- Fast Switching
- PN Junction Guard Ring Transient and ESD Protection
- Designed for Surface Mount Application
- Plastic Material —UL Recognition Flammability Classification 94V-O
- Green Products in Compliance with the ROHS Directive
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Mechanical Data

- Case: SOD-123, Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202,

Method 208

Polarity: Cathode BandWeight: 0.01 grams(approx)

Maximum Ratings and Electrical Characteristics @T_A=25°C unless otherwise specified

Characteristic	Symbol	MBR130HW	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	30	V
Forward Continuous Current(Note1)	I _F	1.0	Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load(JEDEC Method)	I _{FSM}	25	А
Power Dissipation(Note1)	P _D	450	mW
Typical Thermal Resistance, Junction to Ambient Air(Note1)	R _{θJA}	222	°C/W
Junction and Storage Temperature Range	TJ, TSTG	-65 to +125	°C

Characteristic		Symbol	Тур.	Max.	Unit
Forward Voltage Drop	@I _F =1.0A	V _{FM}	0.44	0.45	V
Peak Reverse Leakage Current @DC Blocking Voltage		I _{RM}	0.01	0.4	mA
Junction Capacitance(V _R =4V DC, f=1MHz)		CJ	50	-	pF

Note: 1. Valid provided that terminals are kept at ambient temperature.

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Ratings and Characteristics Curves

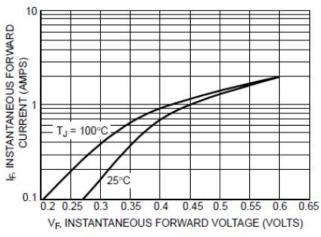


Figure 1. Maximum Forward Voltage

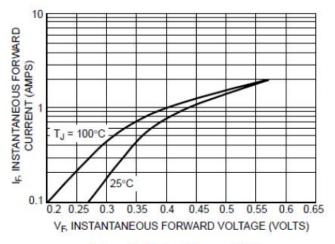


Figure 2. Typical Forward Voltage

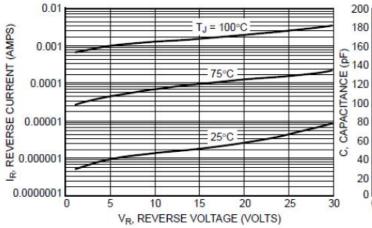


Figure 3. Typical Reverse Current

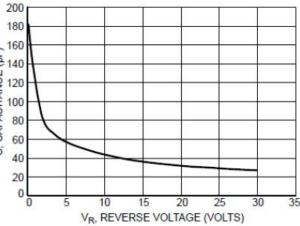


Figure 4. Typical Capacitance

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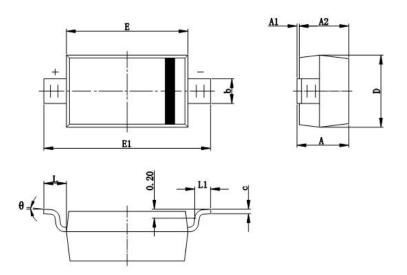
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Mechanical Dimensions SOD-123



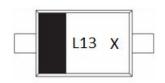
OVMDOL	Millimeters		Inches	
SYMBOL	MIN.	MAX.	MIN.	MAX.
Α	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.450	0.650	0.018	0.026
С	0.080	0.150	0.003	0.006
D	1.500	1.700	0.059	0.067
Е	2.600	2.800	0.102	0.110
E1	3.550	3.850	0.140	0.152
L	0.500 REF.		0.020 REF.	
L1	0.250	0.450	0.010	0.018
θ	0°	8°	0°	8°

Ordering Information

Device	Package	Shipping
MBR130HW	SOD-123 (Pb-Free)	3000pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram

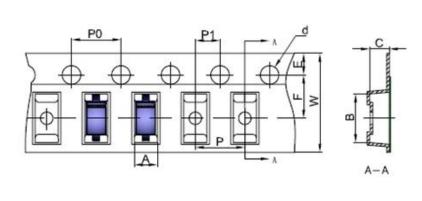


Where X is Date Code

L13 = Part Name

MBR130HW

Carrier Tape Specification SOD-123



SYMBOL	Millimeters		
STWIBUL	Min.	Max.	
Α	1.80	1.90	
В	3.89	3.99	
С	1.52	1.62	
d	1.45	1.65	
E	1.65	1.85	
F	3.40	3.60	
Р	3.90	4.10	
P0	3.90	4.10	
P1	1.90	2.10	
W	7.90	8.30	

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